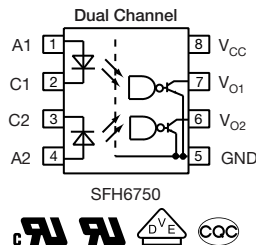
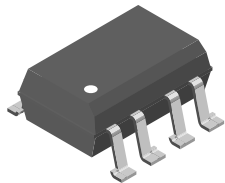




High Speed Optocoupler, Dual, 10 MBd



FEATURES

- CMR performance of 100 V/ μ s
- High speed: 10 MBd typical
- +5 V CMOS compatibility
- Pure tin leads
- Guaranteed AC and DC performance over temperature: -40 °C to +100 °C
- Meets IEC 60068-2-42 (SO₂) and IEC 60068-2-43 (H₂S) requirements
- Low input current capability: 5 mA
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

APPLICATIONS

- Microprocessor system interface
- PLC, ATE input / output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- Ground loop elimination

AGENCY APPROVALS

- [UL](#)
- [cUL](#)
- [DIN EN 60747-5-5 \(VDE 0804\)](#), available with option 1
- [BSI](#)
- [CQC GB4943.1](#)
- [CQC GB8898](#)

LINKS TO ADDITIONAL RESOURCES

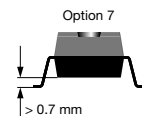

[Product Page](#)

DESCRIPTION

The SFH675x are single and dual channel 10 MBd optocouplers utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transistor output, providing less leakage compared to an open collector Schottky clamped transistor output. For the single channel type, an enable function on pin 7 allows the detector to be strobed. The internal shield provides a guaranteed common mode transient immunity of 100 V/ μ s for the SFH6750.

ORDERING INFORMATION

S	F	H	6	7	#	#	-	X	0	0	#	T
PART NUMBER								PACKAGE OPTION				TAPE AND REEL



AGENCY CERTIFIED / PACKAGE	DUAL CHANNEL
	CMR (kV/ μ s)
BSI, UL, cUL	0.1
SMD-8, option 7	SFH6750-X007T

Note

- For additional information on the available options refer to option information

**TRUTH TABLE** (positive logic)

LED	ENABLE	OUTPUT
On	H	L
Off	H	H
On	L	H
Off	L	H
On	NC	L
Off	NC	H

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Average forward current (single channel)		I_F	20	mA
Average forward current (per channel for dual channel)		I_F	15	mA
Reverse input voltage		V_R	5	V
Enable input voltage (single channel)		V_E	$V_{CC} + 0.5\text{ V}$	V
Enable input current (single channel)		I_E	5	mA
Surge current	$t = 100\text{ }\mu\text{s}$	I_{FSM}	200	mA
OUTPUT				
Supply voltage		V_{CC}	7	V
Output current		I_O	50	mA
Output voltage		V_O	7	V
Output power dissipation (single channel)		P_{diss}	85	mW
Output power dissipation per channel (dual channel)		P_{diss}	60	mW
COUPLER				
Storage temperature		T_{stg}	-55 to +150	$^{\circ}\text{C}$
Operating temperature		T_{amb}	-40 to +100	$^{\circ}\text{C}$
Lead solder temperature (single channel)	For 10 s		260	$^{\circ}\text{C}$
Solder reflow temperature ⁽¹⁾	For 1 min		260	$^{\circ}\text{C}$
Isolation test voltage	$t = 1\text{ min}$	V_{ISO}	5300	V_{RMS}

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

RECOMMENDED OPERATING CONDITIONS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT
Operating temperature		T_{amb}	-40	100	$^{\circ}\text{C}$
Supply voltage		V_{CC}	4.5	5.5	V
Input current low level		I_{FL}	0	250	μA
Input current high level		I_{FH}	5	15	mA
Logic high enable voltage		V_{EH}	2	V_{CC}	V
Logic low enable voltage		V_{EL}	0	0.8	V
Output pull up resistor		R_L	330	4K	Ω
Fanout	$R_L = 1\text{ k}\Omega$	N		5	-



ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Input forward voltage	$I_F = 10\text{ mA}$	V_F	1	1.4	1.7	V
Reverse current	$V_R = 5\text{ V}$	I_R	-	0.01	10	μA
Input capacitance	$f = 1\text{ MHz}$, $V_F = 0\text{ V}$	C_I	-	55	-	pF
OUTPUT						
High level supply current (single channel)	$V_E = 0.5\text{ V}$, $I_F = 0\text{ mA}$	I_{CCH}	-	4.1	7	mA
	$V_E = V_{CC}$, $I_F = 0\text{ mA}$	I_{CCH}	-	3.3	6	mA
High level supply current (dual channel)	$I_F = 0\text{ mA}$	I_{CCH}	-	6.9	12	mA
Low level supply current (single channel)	$V_E = 0.5\text{ V}$, $I_F = 10\text{ mA}$	I_{CCL}	-	4	7	mA
	$V_E = V_{CC}$, $I_F = 10\text{ mA}$	I_{CCL}	-	3.3	6	mA
Low level supply current (dual channel)	$I_F = 10\text{ mA}$	I_{CCL}	-	6.5	12	mA
High level output current	$V_E = 2\text{ V}$, $V_O = 5.5\text{ V}$, $I_F = 250\text{ }\mu\text{A}$	I_{OH}	-	0.002	1	μA
Low level output voltage	$V_E = 2\text{ V}$, $I_F = 5\text{ mA}$, $I_{OL}(\text{sinking}) = 13\text{ mA}$	V_{OL}	-	0.2	0.6	V
Input threshold current	$V_E = 2\text{ V}$, $V_O = 5.5\text{ V}$, $I_{OL}(\text{sinking}) = 13\text{ mA}$	I_{TH}	-	2.4	5	mA
High level enable current	$V_E = 2\text{ V}$	I_{EH}	-	-0.6	-1.6	mA
Low level enable current	$V_E = 0.5\text{ V}$	I_{EL}	-	-0.8	-1.6	mA
High level enable voltage		V_{EH}	2	-	-	V
Low level enable voltage		V_{EL}	-	-	0.8	V

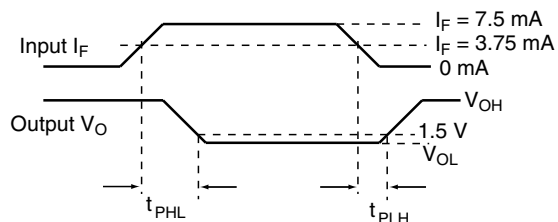
Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements; all typicals at $T_{amb} = 25\text{ }^{\circ}\text{C}$, $V_{CC} = 5.5\text{ V}$, unless otherwise specified.

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to high output level	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	t_{PLH}	20	48	100	ns
Propagation delay time to low output level	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	t_{PHL}	25	50	100	ns
Pulse width distortion	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	$ t_{PHL} - t_{PLH} $	-	2.9	35	ns
Propagation delay skew	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	t_{PSK}	-	8	40	ns
Output rise time (10 % to 90 %)	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	t_r	-	23	-	ns
Output fall time (90 % to 10 %)	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$	t_f	-	7	-	ns
Propagation delay time of enable from V_{EH} to V_{EL}	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$, $V_{EL} = 0\text{ V}$, $V_{EH} = 3\text{ V}$	t_{ELH}	-	12	-	ns
Propagation delay time of enable from V_{EL} to V_{EH}	$R_L = 350\text{ }\Omega$, $C_L = 15\text{ pF}$, $V_{EL} = 0\text{ V}$, $V_{EH} = 3\text{ V}$	t_{EHL}	-	11	-	ns

Note

- Over recommended temperature ($T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+100\text{ }^{\circ}\text{C}$), $V_{CC} = 5\text{ V}$, $I_F = 7.5\text{ mA}$ unless otherwise specified; all typicals at $T_{amb} = 25\text{ }^{\circ}\text{C}$, $V_{CC} = 5\text{ V}$



18964-2

The diagram shows a Dual Channel device with 8 pins. Pins 1 and 2 are labeled 'Input Monitoring Node' and are connected to a resistor R_M . Pins 3 and 4 are labeled 'Pulse Gen.' and are connected to a pulse generator. The pulse generator is specified with $Z_O = 50 \Omega$ and $t_f = t_r = 5 \text{ ns}$. The output of the device is taken from pins 7 and 8, labeled 'Output V_O Monitoring Node', and is connected to a load resistor R_L . The device is powered by V_{CC} (pin 8) and grounded (pin 5). A $0.1 \mu\text{F}$ bypass capacitor is connected between pins 6 and 5. A load capacitor $C_L = 15 \text{ pF}$ is connected between the output node and ground. The device is labeled 'Dual Channel' and 'VCC'.

Pulse gen.
 $Z_o = 50 \Omega$
 $t_f = t_r = 5 \text{ ns}$

Input V_E
 monitoring node

Single channel

7.5 mA
 I_F

Output V_O
 monitoring node

V_{CC}
 V_E
 V_{OUT}
 GND

R_L
 0.1 μF bypass
 $C_L = 15 \text{ pF}$

18975-2



COMMON MODE TRANSIENT IMMUNITY						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode transient immunity (high)	$ V_{CM} = 10 \text{ V}$, $V_{CC} = 5 \text{ V}$, $I_F = 0 \text{ mA}$, $V_{O(\min.)} = 2 \text{ V}$, $R_L = 350 \Omega$, $T_{\text{amb}} = 25^\circ\text{C}$ (1)	$ CM_H $	100	-	-	V/ μs
	$ V_{CM} = 50 \text{ V}$, $V_{CC} = 5 \text{ V}$, $I_F = 0 \text{ mA}$, $V_{O(\min.)} = 2 \text{ V}$, $R_L = 350 \Omega$, $T_{\text{amb}} = 25^\circ\text{C}$ (2)	$ CM_H $	5000	10 000	-	V/ μs
	$ V_{CM} = 10 \text{ V}$, $V_{CC} = 5 \text{ V}$, $I_F = 7.5 \text{ mA}$, $V_{O(\max.)} = 0.8 \text{ V}$, $R_L = 350 \Omega$, $T_{\text{amb}} = 25^\circ\text{C}$ (1)	$ CM_L $	100	-	-	V/ μs
	$ V_{CM} = 50 \text{ V}$, $V_{CC} = 5 \text{ V}$, $I_F = 7.5 \text{ mA}$, $V_{O(\max.)} = 0.8 \text{ V}$, $R_L = 350 \Omega$, $T_{\text{amb}} = 25^\circ\text{C}$ (2)	$ CM_L $	5000	10 000	-	V/ μs

Notes

(1) For SFH6750

(2) For SFH6741

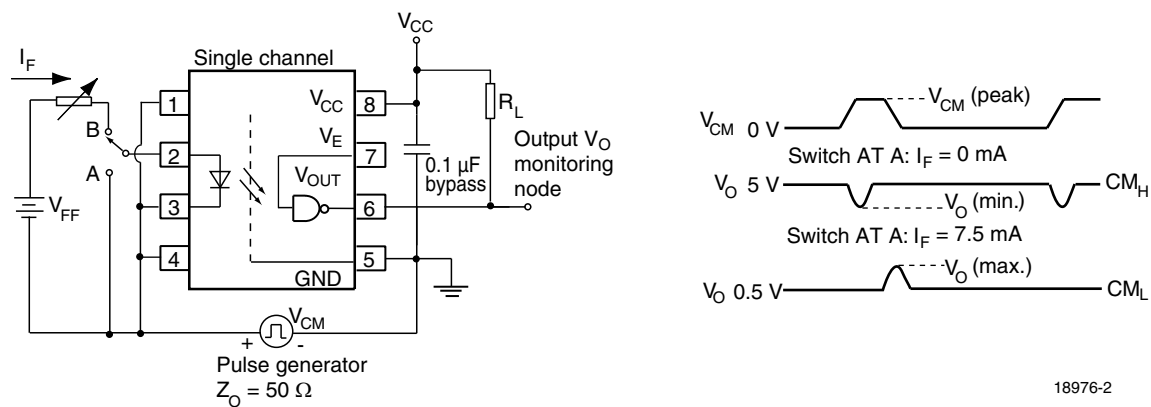


Fig. 4 - Single Channel Test Circuit for Common Mode Transient Immunity

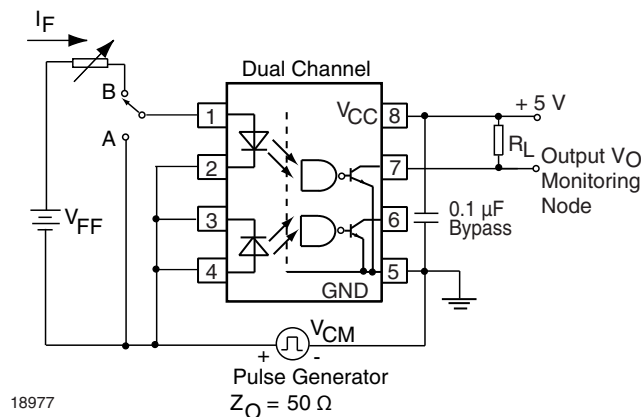


Fig. 5 - Dual Channel Test Circuit for Common Mode Transient Immunity



SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification	According to IEC 69 part 1		-	40 / 100 / 21	-	
Comparative tracking index		CTI	175	-	399	
Peak transient overvoltage		V_{IOTM}	8000	-	-	V
Peak insulation voltage		V_{IORM}	630	-	-	V
Safety rating - power output		P_{SO}	-	-	500	mW
Safety rating - input current		I_{SI}	-	-	300	mA
Safety rating - temperature		T_{SI}	-	-	175	°C
Creepage distance	DIP-8, 400 mil, option 6		8	-	-	mm
Clearance distance			8	-	-	mm
Creepage distance	SMD-8, option 7		8	-	-	mm
Clearance distance			8	-	-	mm
Insulation thickness, reinforced rated	Per IEC 60950.2.10.5.1		0.4	-	-	mm

Note

- As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

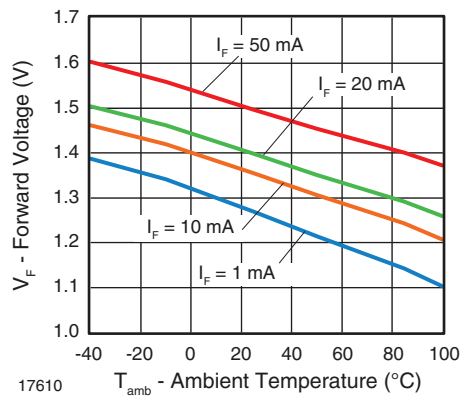
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)

Fig. 6 - Forward Voltage vs. Ambient Temperature

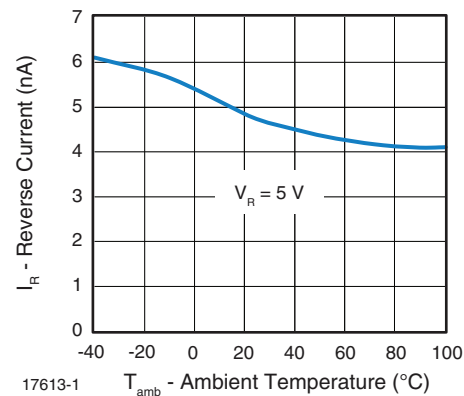


Fig. 8 - Reverse Current vs. Ambient Temperature

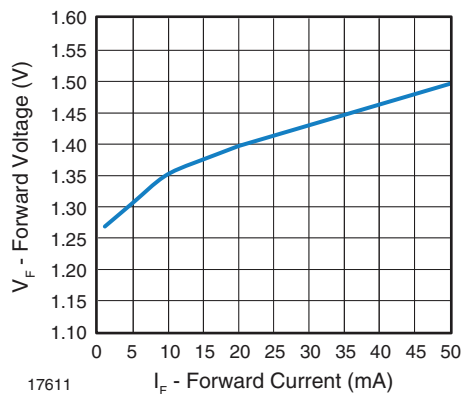


Fig. 7 - Forward Voltage vs. Forward Current

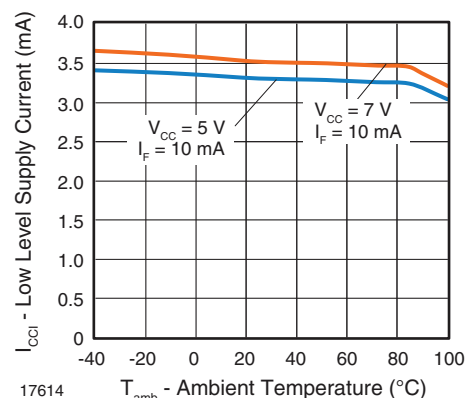




Fig. 9 - Low Level Supply Current vs. Ambient Temperature

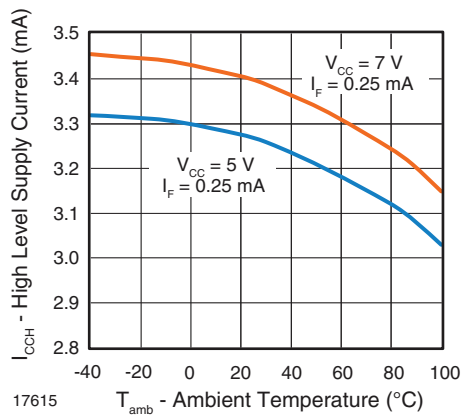


Fig. 10 - High Level Supply Current vs. Ambient Temperature

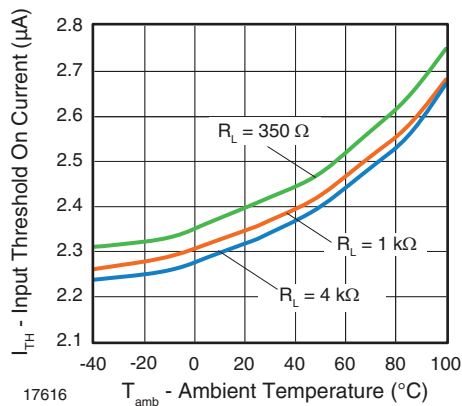


Fig. 11 - Input Threshold On Current vs. Ambient Temperature

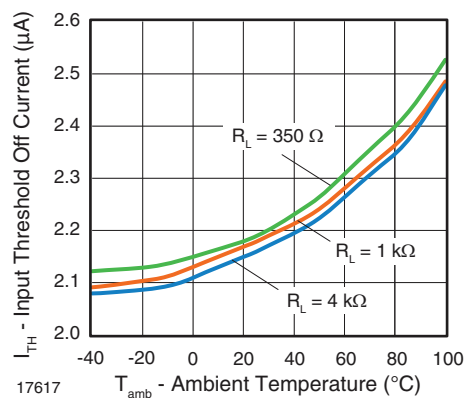


Fig. 12 - Input Threshold Off Current vs. Ambient Temperature

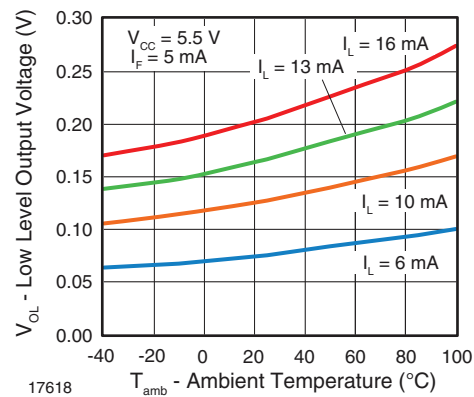


Fig. 13 - Low Level Output Voltage vs. Ambient Temperature

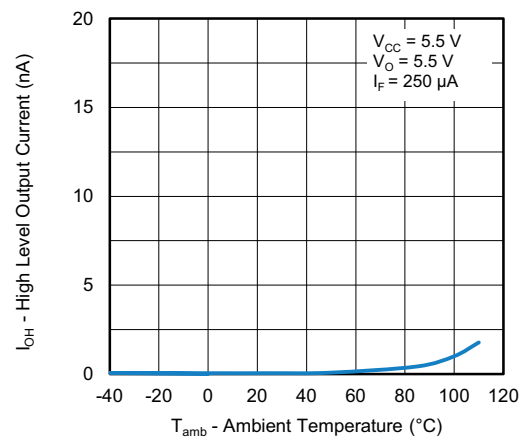


Fig. 14 - Low Level Output Current vs. Ambient Temperature

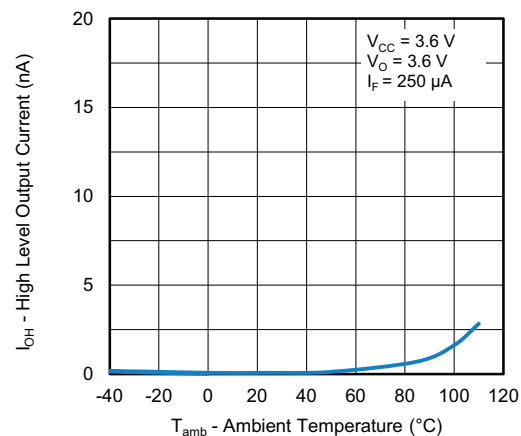


Fig. 15 - High Level Output Current vs. Ambient Temperature

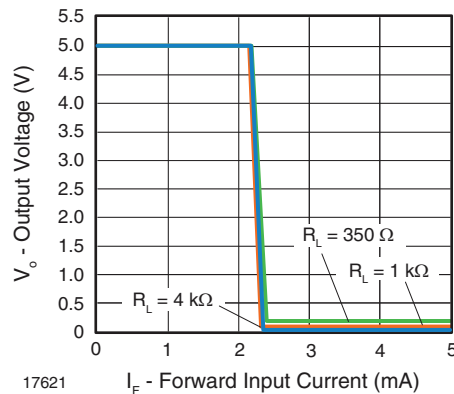


Fig. 16 - Output Voltage vs. Forward Input Current

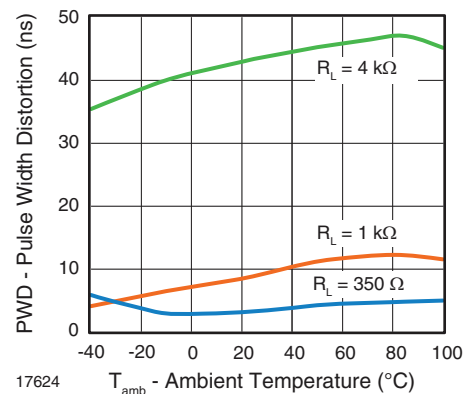


Fig. 19 - Pulse Width Distortion vs. Ambient Temperature

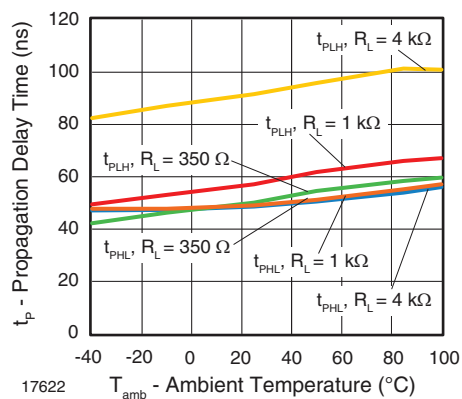


Fig. 17 - Propagation Delay vs. Ambient Temperature

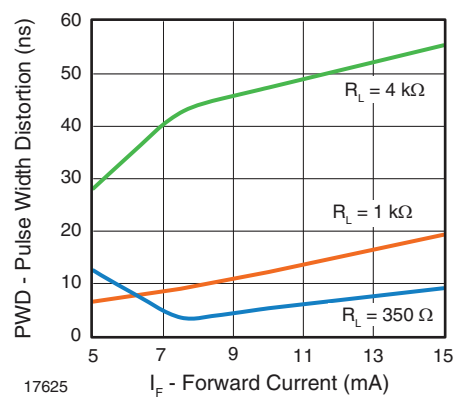


Fig. 20 - Pulse Width Distortion vs. Forward Current

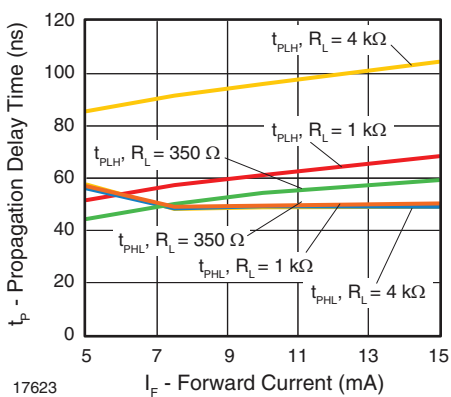


Fig. 18 - Propagation Delay vs. Forward Current

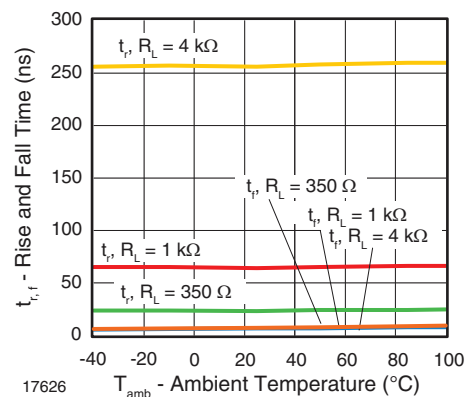


Fig. 21 - Rise and Fall Time vs. Ambient Temperature

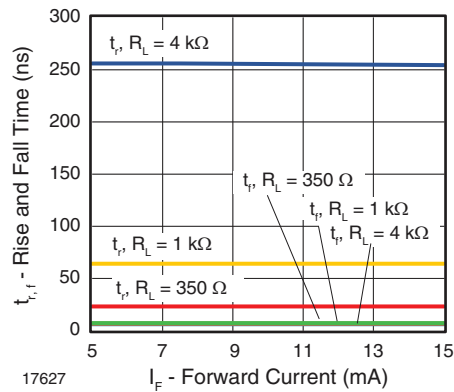


Fig. 22 - Rise and Fall Time vs. Forward Current

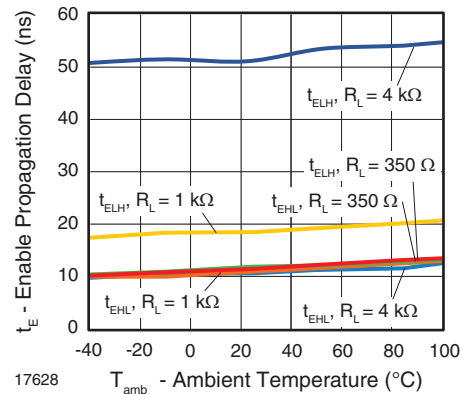
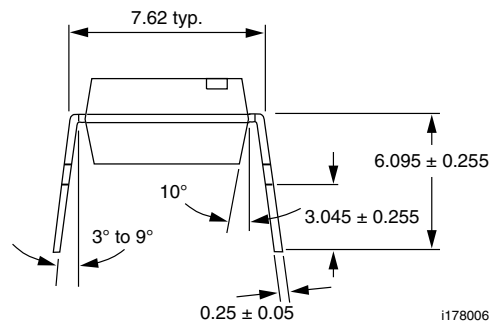
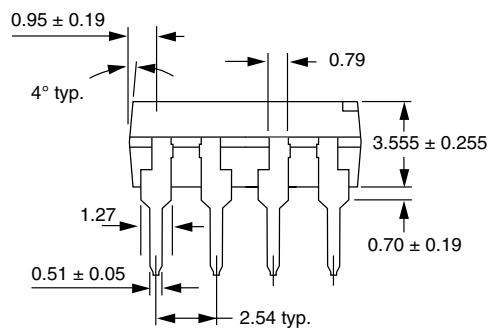
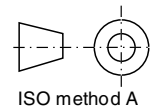
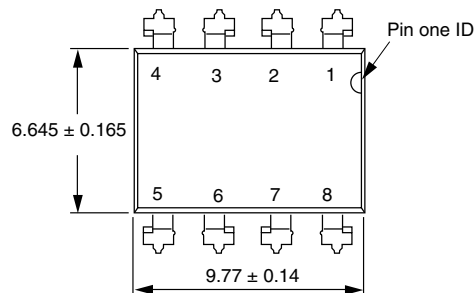
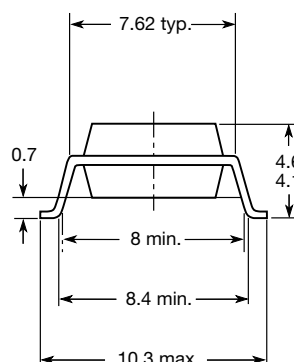
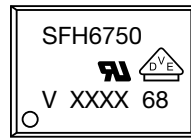


Fig. 23 - Enable Propagation Delay vs. Ambient Temperature

PACKAGE DIMENSIONS in millimeters**Option 7**



PACKAGE MARKING (for example)



Notes

- XXXX = LMC (lot marking code)
- VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.